

#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	Rds(ON) Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C		
60V	2Ω @ V <sub>GS</sub> = 5.0V	350mA		
60 v	2.5Ω @ V <sub>GS</sub> = 2.5V	550IIA		

#### Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

#### Applications

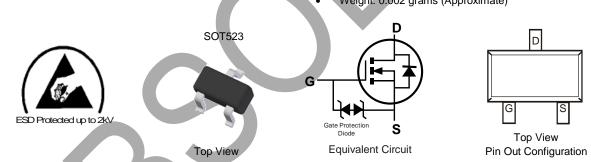
- Motor controls
- Power-management functions

#### **Features**

- Low On-Resistance: RDS(ON)
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



# Ordering Information (Note 4)

Part Number	Bookago	Packing				
Part Number	Package	Qty.	Carrier			
DMN61D9UT-7	SOT523	3000	Tape & Reel			
DMN61D9UT-13	SOT523	10000	Tape & Reel			

Notes:

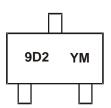
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**



9D2 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: K = 2023) M = Month (ex: 9 = September)

### Date Code Kev

Dale Code Key												
Year	2015	-	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	С	-	К	L	М	Ν	0	Р	R	S	Т	U
	1											
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D
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### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	Vdss	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 5) V <sub>GS</sub> = 5.0V	lb	350 280	mA	
Maximum Continuous Body Diode Forward Currer	nt (Note 5)	ls	350	mA
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)	Ідм	1.1	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	260	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	491	°C/W
Total Power Dissipation (Note 5)		PD	370	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	342	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

 Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. copper, single sided.
Device mounted on FR-4 PCB, with minimum recommended pad layout. Notes:



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

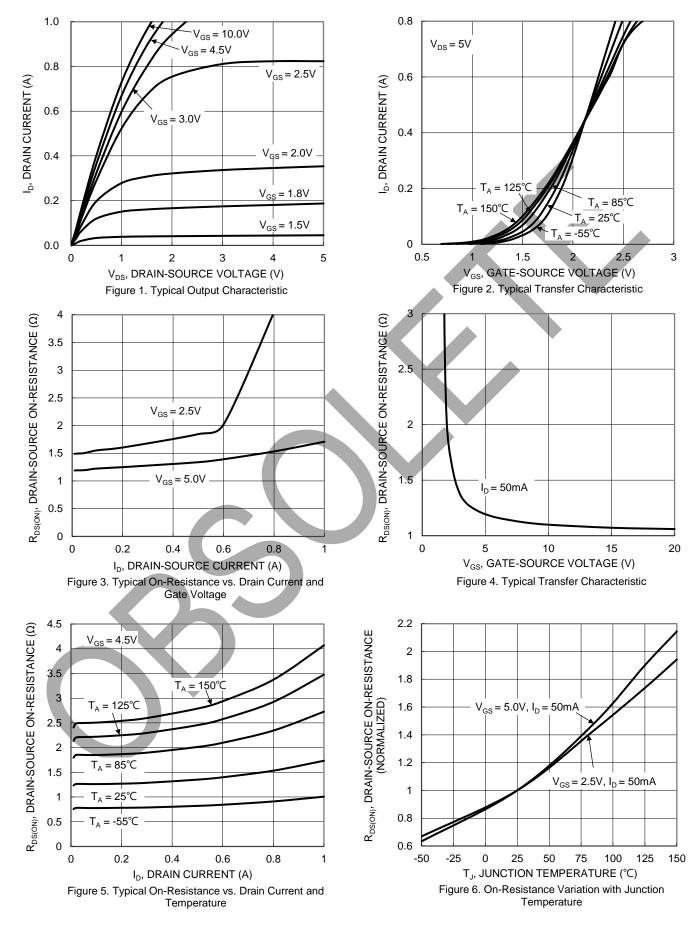
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						•
Drain-Source Breakdown Voltage	BVDSS	60	_		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	Igss			±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5		1.0	V	$V_{DS} = 10V$ , $I_{D} = 250\mu A$
		_	1.2	2.0		$V_{GS} = 5.0V, I_D = 0.05A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	1.6	2.5	Ω	$V_{GS} = 2.5V, I_D = 0.05A$
		—	2.5	3.5		Vgs = 1.8V, ID = 0.05A
Forward Transconductance	Y <sub>fs</sub>	200			mS	$V_{DS} = 10V, I_{D} = 0.2A$
Diode Forward Voltage	Vsd		0.75	1.4	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 115mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	28.5		pF	
Output Capacitance	Coss		3.9	Y	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	-	2.5		pF	
Gate Resistance	Rg	—	65		Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	Qg	-	0.4		nC	
Gate-Source Charge	Q <sub>gs</sub>		0.1		nC	Vgs = 4.5V, Vps = 10V Ip = 250mA
Gate-Drain Charge	Q <sub>gd</sub>		0.1	-	nC	10 = 23011A
Turn-On Delay Time	tD(ON)	_	2.1	_	ns	
Turn-On Rise Time	tr	—	1.8		ns	V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V
Turn-Off Delay Time	tD(OFF)	—	14.4		ns	$R_g = 25\Omega, I_D = 200mA$
Turn-Off Fall Time	tF	—	8.4	—	ns	

Notes:

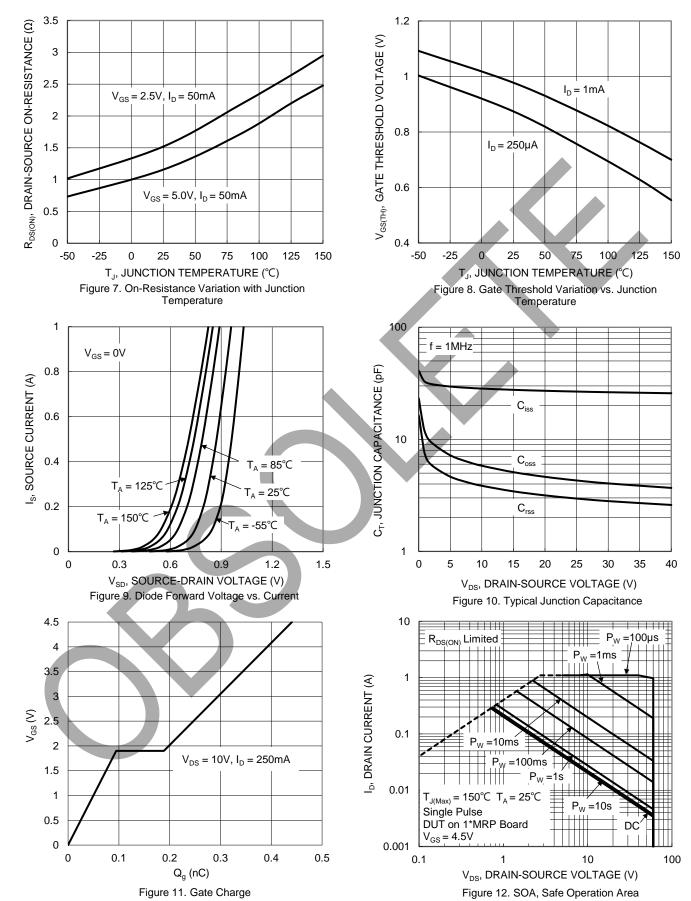
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.



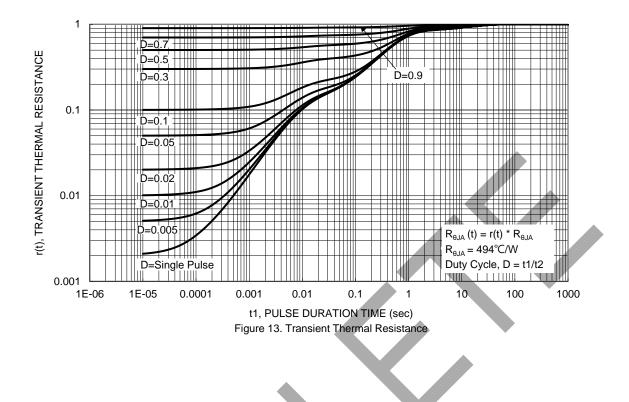
# DMN61D9UT









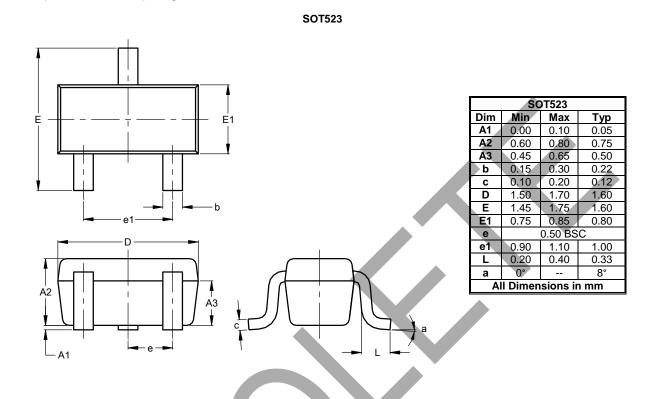


DMN61D9UT Document number: DS38185 Rev. 5 - 4



### **Package Outline Dimensions**

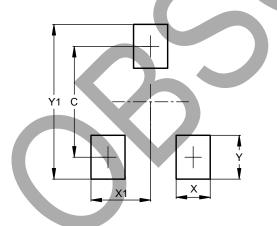
Please see http://www.diodes.com/package-outlines.html for the latest version.



# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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